





Day 1 – Tuesday 21st May 2024

Time	Location: Aerial Centre, UTS				
8:30	Registration and welcome coffee				
9:00	BNW2024 Opening remarks – Igor Aharonovich				
	Boron Nitride Devices (Session Chair – Guillaume Cassabois)				
9:20	Invited Speaker – Siyuan Dai "Engineering phonon polaritons in hBN van der Waals structures"				
9:50	Contributed talk – Joshua Caldwell "Ultrafast Thermal Dissipation via Surface Phonon Polaritons"				
10:10	Contributed talk - Myungsoo Kim "BN for memory, computing and radiofrequency switches"				
10:30	COFFEE BREAK				
	Growth and Color Centres 1 (Session Chair – Young Duck Kim)				
11:10	Invited Speaker – Wen Hao Chang "CVD-grown hBN for 2D transistors and quantum emitters""				
11:40	Invited Speaker – Jieun Lee "Electrical control of light emission from h-BN single photon sources"				
12:10	Contributed talk – Gyuna Park "Room temperature EL from isolated colour centres in van der Waals semiconductors"				
12:30	LUNCH				
	Computational Modelling (Session Chair – Francisco Javier Muñoz Sáez)				
14:00	Invited Speaker – Viktor Ivady "Computational exploration of hBN defects: insights into topological defects, spins, and emitters				
14:30	Invited Speaker – Ludger Wirtz "Exciton-phonon coupling in boron nitride"				
15:00	Contributed talk – Sheng-Shong Wong "The electronic band structure of mono-, bi-, and trilayer h-BN"				
15:20	Contributed talk – Seokho Moon "Wafer-Scale AA-Stacked Hexagonal Boron Nitride Grown on GaN Substrate"				
15:40	Round table with Q&A, facilitated by the chairs of the session				
16:30	Welcome Reception, Aerial Centre, UTS				

Day 2 – Wednesday 22nd May 2024

Time	Location: Aerial Centre, UTS				
	Growth and Color Centres 2 (Session Chair – Andrzej Wysmolek)				
9:00	Invited Speaker – Young Duck Kim "Manipulation of carbon color centers in hexagonal boron nitride"				
9:30	Invited Speaker – Francisco Javier Muñoz Sáez "Carbon-based single photon emitters in hBN and van der Waals heterostructures"				
10:00	Contributed talk – Jonathan Bradford "MBE of carbon-doped hBN on HOPG: Insights into the atomic structure of SPEs"				
10:20	Contributed talk – Camile Maestre "Searching for diffuse defects in millimetre-sized h-BN crystals"				
10:40	COFFEE BREAK				
	Cubic Boron Nitride (Session Chair – Ying (Ian) Chen)				
11:10	Invited Speaker – Kazuyuki Hirama "c-BN epitaxial growth mechanism in ion-beam-assisted MBE"				
11:40	Invited Speaker – Siddha Pimpukar "Growth of Bulk Boron Nitride"				
12:10	Invited Speaker – Kaihui Liu "Optical Crystals of Two-dimensional Rhombohedral Boron Nitride"				
12:40	LUNCH				
Spin defects in hBN (Session Chair – Jieun Lee)					
14:00	Contributed talk – Tongcang Li "Quantum sensing with single spin defects in boron nitride nanotubes"				
14:20	Contributed talk – Ruotian Gong "Enhancing Coherence Properties of Spin Defects in hBN"				
14:40	Contributed talk – Kento Sasaki "Nitrogen isotopes effects on hBN quantum sensor"				
15:00	Contributed talk – Guillaume Cassabois "Optical and spin properties of boron-vacancy centers in few-layer thick hBN"				
15:20	Contributed talk – Islay Robertson "Spin Properties of visible emitters in hBN"				
15:40	Round table with Q&A, facilitated by the chair of the session + summary of the day				
16:30	Poster session + Wine/Canapes, Aerial Centre, UTS				

Time	Location: Aerial Centre, UTS					
	Growth (Session Chair – Wen Hao Chang)					
9:00	Invited Speaker – Andrzej Wysmolek "MOVPE growth and applications of layered boron nitride"					
9:30	Invited Speaker – Pengfei Yang "Controllable growth of uniform multilayer hexagonal boron nitride on metals and insulators"					
10:00	Contributed talk – Simonas Krotkus "Interfacial engineering for wafer scale synthesis of multilayer sp2 -BN films"					
10:20	Contributed talk – George Bepete "Chemical intercalation, exfoliation, and functionalization of hBN materials"					
10:40	COFFEE BREAK					
	hBN Nanophotonics (Session Chair – Joshua Caldwell)					
11:20	Invited Speaker – Valentyn Volkov "hBN Nanophotonics: UV Transparency, High Refractive Index and Optical Anisotropy"					
11:50	Invited Speaker – Stefan Maier "Tunability and applications of hBN metasurfaces"					
12:20	Contributed talk – Lesley Spencer "Monolithic Integration of Single Quantum Emitters in hBN Bullseye Cavities"					
12:40	LUNCH					
Future Applications of Boron Nitride (Session Chair – Stefan Maier)						
14:00	Invited Speaker – Ying (Ian) Chen "Boron nitride nanomaterials for energy applications"					
14:30	Invited Speaker – Tomoki Machida "hBN in van der Waals Heterostructures"					
15:00	Contributed talk – Eveline Mayner "Optical Readout of Redox Reaction via hBN Surface Emitters"					
15:20	Contributed talk – Kristina Malinowski "Photon statistics analysis of h-BN emitters with pulsed and cw excitation through Mandel Q"					
15:40	Round table with Q&A, facilitated by the chair of the session + summary of the day					
16:30	Concluding remarks and plans for Future hBN meetings					
	17:30 - 19:30 BBQ Dinner, Universal Cafeteria (building 6)					

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Poster Presentations

N°	Presenter name	Title
1	Sergei Nedic	Electron Beam Restructuring of Quantum Emitters in Hexagonal Boron Nitride
2	Guillaume Cassabois	Spatially-resolved UV-C emission in epitaxial monolayer boron nitride
3	Qiran Cai	Thermal property and applications of boron nitride nanosheets
4	Roy Styles	The effect of electric fields on visible spin defects in hBN
5	Guillaume Cassabois	What is the nature of the UV color center emitting at 300 nm in hexagonal boron nitride ?
6	Christopher J. Mellor	Single photon emitters created by intentional carbon doping of hBN grown on sapphire by high-T MBE
7	Kabilan Sripathy	QUICK3 – Towards satellite-based quantum communication, and fundamental physics tests in microgravity
8	Rotem Malkinson	Systematically creating boron vacancies in bulk exfoliated hBN flakes using focused ion beam
9	Paul Konrad	Quantum Sensors in hBN: Intersystem Crossing Relaxation of the Metastable State and Irradiation Protocol
10	Jakub Rogoża	Conductivity induced by post growth annealing of boron nitride grown by MOVPE
11	Sonachand Adhikari	hBN-Enabled Flexible GaN Photodetector
12	Fei Kong	Optimal sensitivity of a spin sensor with high fidelity quantum controls
13	Jakub Iwański	Polytype Identification in MOVPE Grown sp2-BN Using Ultraviolet Defect Photoluminescence
14	Qiran Cai	Boron nitride nanosheet aggregates for enhanced acoustic energy harvesting
15	Hayoung Ko	Growth of wafer-scale, high-quality, multilayer hBN on liquid Fe2B for high-performance of 2D heterostructure
16	Pragya Joshi	Carbon Migration and Single Photon Emission in Electron Irradiated hBN flakes
17	Jong Sung Moon	Fiber-integrated quantum sensors using color centers with optimal cavity interface
18	Bindu Bindu	Quantum Sensing and Imaging of van der Waals Ferromagnet using Nitrogen-Vacancy Centers
19	Galya Haim	Exploring methods for creation of Boron-vacancies in hexagonal Boron Nitride exfoliated from bulk crystal

20	Momoko Onodera	Evaluation of hexagonal boron nitride in van der Waals junctions of 2D materials
21	Juliette Plo	Nitrogen isotope effects on hexagonal boron nitride
22	Min-Jae Maeng	Transport band gap measurement of large-area hBN using direct and inverse photoemission spectroscopy
23	Richard Escalante	Sensitivity Optimization of Boron Vacancy Centers in Hexagonal Boron Nitride
24	Andrew Beling	Toward Nanoscale NMR Spectroscopy using the Boron Vacancy Quantum Defect in hBN
25	Jake Horder	Resonant Spectroscopy of B-Center Quantum Emitters in hBN
26	Minhyun Cho	Remote moire effect engineering using the twisted hBN
27	YoungJae Kim	High electric field vertical tunneling transports in hexagonal boron nitride
28	Heeyeon Lee	Hexagonal boron nitride surface engineering for remote modulation doping
29	Shih-Chu Lin	Defect engineering in CVD-Grown Hexagonal Boron Nitride for Quantum Photonic Applications
30	Dominic Scognamiglio	Controlling and stabilizing the Charge State of Spin Defects in hBN
31	Seungmin Park	High-efficiency deep ultraviolet emitting from hexagonal boron nitride heterostructure
32	Nils Bernhardt	UV defect emitters in thin hBN
33	Helen Zeng	Hexagonal Boron Nitride-Based Quantum Key Distribution with Room Temperature Single Photon Emission
34	Benjamin Whitefield	Magnetic Field Sensitivity Optimization of Negatively Charged Boron Vacancy Defects in hBN
35	Karin Yamamura	Plasmonic lattices-assisted emission enhancement and optimized creation of blue colour centre in hBN
36	Anand Kumar	Solid states quantum emitters in wide band gap materials for quantum technology applications
37	Madeline Hennessey	Towards Boron Nitride Nanotube Optical Emitters in Sensing Applications
38	Wei Liu	Coherent control of an ultrabright single spin in hexagonal boron nitride at room temperature
39	Ryan Kowalski	Correlating Defect Emission with Infrared Near-Field Imaging in Strained Hexagonal Boron Nitride
40	Takashi Taniguchi	TBD

The prize for the best poster presentation by a PhD student is supported by IOP MQT and 2D Materials journals.

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